

Driver Characteristics

Parameter	Rating	Units
V_{OFFSET}	600	V
$I_{\text{O } \pm}$ (Source/Sink)	250/500	mA
V_{CStH}	250	mV
$t_{\text{ON}} / t_{\text{OFF}}$ (Typical)	100	ns

Features

- Floating Channel Designed for Bootstrap Operation up to 600V
- Tolerant to Negative Transient Voltages; dV/dt Immune
- Undervoltage Lockout
- 3.3V, 5V, and 12V Input Logic Compatible
- Open-Drain FAULT Indicator Pin Shows Over-Current Shutdown
- Output in Phase with the Input

Applications

- High-Speed Gate Driver
- Motor Drive Inverter

Description

The IX2127 is a high-voltage, high-speed power MOSFET and IGBT driver. High-voltage level-shift circuitry enables this device to operate up to 600V. IXYS Integrated Circuits Division's proprietary common-mode design techniques provide stable operation in high dV/dt noise environments.

An on-board comparator can be used to detect an over-current condition in the driven MOSFET or IGBT device, and then shut down drive to that device. An open-drain output, $\overline{\text{FAULT}}$, indicates that an over-current shutdown has occurred.

The gate driver output typically can source 250mA and sink 500mA, which is suitable for fluorescent lamp ballast, motor control, SMPS, and other converter drive topologies.

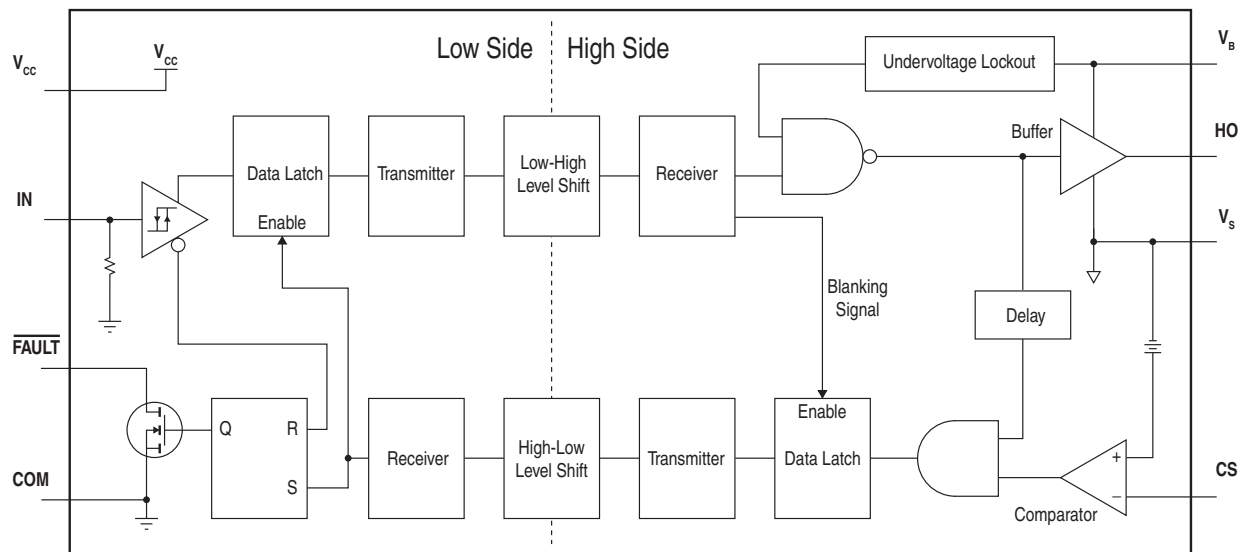
The IX2127 is provided in 8-pin DIP and 8-pin SOIC packages, and is available in Tape & Reel versions. See ordering information below.

Ordering Information

Part	Description
IX2127G	8-Pin DIP (50/Tube)
IX2127N	8-Pin SOIC (100/Tube)
IX2127NTR	8-Pin SOIC (2000/Reel)



IX2127 Block Diagram



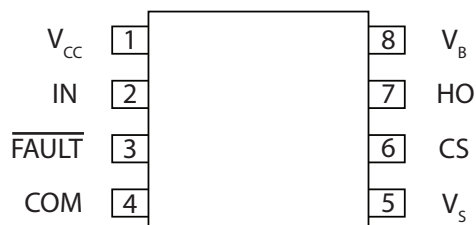


1. Specifications	3
1.1 Package Pinout	3
1.2 Pin Description	3
1.3 Absolute Maximum Ratings	3
1.4 Recommended Operating Conditions	4
1.5 General Conditions	4
1.6 Electrical Characteristics	5
1.7 Timing Characteristics	6
2. Performance Data	8
3. Manufacturing Information	11
3.1 Moisture Sensitivity	11
3.2 ESD Sensitivity	11
3.3 Soldering Profile	11
3.4 Board Wash	11
3.5 Mechanical Dimensions	12



1 Specifications

1.1 Package Pinout



1.2 Pin Description

Pin#	Name	Description
1	V_{CC}	Logic Supply Voltage
2	IN	Logic Input
3	$\overline{FAULT}$	Fault Indicator Output
4	COM	Logic Ground
5	V_S	High Side Return
6	CS	Comparator Input, Over-Current Detect
7	HO	High Side Gate Drive Output
8	V_B	High Side Supply Voltage

1.3 Absolute Maximum Ratings

Unless otherwise specified, ratings are provided at $T_A=25^\circ\text{C}$ and all bias levels are with respect to COM.

Parameter	Symbol	Minimum	Maximum	Units
Logic Supply Voltage	V_{CC}	-0.3	15	V
High Side Floating Supply Voltage	V_B	-0.3	625	
High Side Floating Offset Voltage	V_S	V_B-12	$V_B+0.3$	
Logic Input Voltage	V_{IN}	-0.3	$V_{CC}+0.3$	
High Side Floating Output Voltage	V_{HO}	$V_S-0.3$	$V_B+0.3$	
Current Sense Voltage	V_{CS}	$V_S-0.3$	$V_B+0.3$	
$\overline{FAULT}$ Output Voltage	V_{FLT}	-0.3	$V_{CC}+0.3$	
Allowable Offset Supply Voltage Transient	dV_S/dt	-	50	V/ns
Package Power Dissipation	P_D	-	1	W
8-Lead DIP			0.625	
8-Lead SOIC				
Junction Temperature	T_J	-	150	$^\circ\text{C}$
Storage Temperature	T_S	-55	150	

Absolute maximum electrical ratings are at 25°C

Absolute maximum ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.



1.4 Recommended Operating Conditions

Parameter	Symbol	Minimum	Maximum	Units
Logic Supply	V_{CC}	9	12	V
High Side Floating Supply	V_B	V_S+9	V_S+12	
High Side Offset Voltage	V_S	-5	600	
Logic Input Voltage	V_{IN}	0	V_{CC}	
High Side Floating Output	V_{HO}	V_S	V_B	
Current Sense Signal Voltage	V_{CS}	V_S	V_S+5	
$\overline{FAULT}$ Output Voltage	V_{FLT}	0	V_{CC}	
Ambient Temperature	T_A	-40	+125	°C

1.5 General Conditions

Typical values are characteristic of the device at 25°C and are the result of engineering evaluations. They are provided for information purposes only and are not part of the manufacturing testing requirements.

Unless otherwise noted, all electrical specifications are listed for $T_A=25^\circ\text{C}$.



1.6 Electrical Characteristics

Unless otherwise specified, the test conditions are: $V_{CC}=V_{BS}=12V$; V_{CC} , IN, $\overline{FAULT}$, and Leakage voltages and currents are referenced to COM; V_B , HO, and CS voltages and currents are referenced to V_S .

1.6.1 Power Supply Specifications

Parameter	Conditions	Symbol	Minimum	Typical	Maximum	Units
Quiescent V_{CC} Supply Current	$V_{IN}=0V$	I_{QCC}	-	280	400	μA
Quiescent V_{BS} Supply Current	$V_{IN}=0V$	I_{QBS}	-	500	1000	
V_{BS} UVLO Positive-Going Threshold	-	V_{BS_UV+}	6.8	7.7	8.6	V
V_{BS} UVLO Negative-Going Threshold	-	V_{BS_UV-}	6.3	7.2	8.1	
Offset Supply Leakage Current	$V_B=V_S=600V$	I_{LKG}	-	-	2	μA

1.6.2 Gate Drive and Shutdown Specifications

Parameter	Conditions	Symbol	Minimum	Typical	Maximum	Units
High Level Output Voltage, V_B-V_{HO}	$I_{HO}=0A$	V_{OH}	-	-	100	mV
Low Level Output Voltage, V_{HO}	$I_{HO}=0A$	V_{OL}	-	-	100	
Output Short Circuit Pulsed Current	$V_{HO}=0V$, $V_{IN}=5V$, $PW \leq 10\mu s$, $R_{GATE}=20\Omega^*$ (see Figure 1)	I_{HO+}	-200	-250	-	mA
	$V_{HO}=12V$, $V_{IN}=0V$, $PW \leq 10\mu s$, $R_{GATE}=20\Omega^*$ (see Figure 1)	I_{HO-}	420	500	-	
CS Input, Positive-Going Threshold	$V_{CC}=9V$ to $12V$	V_{CS_TH+}	180	260	320	mV
"High" CS Bias Current	$V_{CS}=3V$	I_{CS+}	-	-	1	μA
	$V_{CS}=0V$	I_{CS-}	-	-	-1	

* R_{GATE} value must be 20Ω or greater.

1.6.3 Logic I/O Specifications

Parameter	Conditions	Symbol	Minimum	Typical	Maximum	Units
Logic "1" Input Voltage	$V_{CC}=9V$ to $12V$	V_{IH}	3.0	-	-	V
Logic "0" Input Voltage	$V_{CC}=9V$ to $12V$	V_{IL}	-	-	0.8	
Logic "1" Input Bias Current	$V_{IN}=5V$	I_{IN+}	-	2.6	15	μA
Logic "0" Input Bias Current	$V_{IN}=0V$	I_{IN-}	-	-	-1	
$\overline{FAULT}$ On-Resistance	-	FLT, R_{ON}	-	72	-	Ω

1.6.4 Thermal Specifications

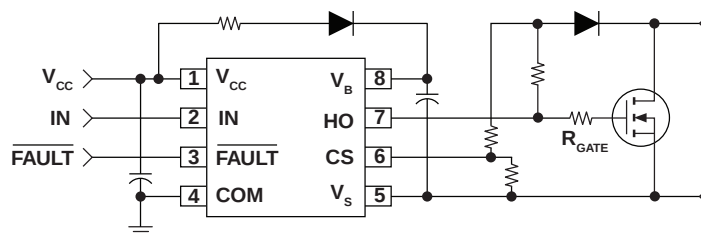
Parameter	Conditions	Symbol	Minimum	Typical	Maximum	Units
Thermal Resistance, Junction to Ambient: 8-Lead DIP 8-Lead SOIC	-	$R_{\theta JA}$	-	-	125	$^{\circ}C/W$
			-	-	200	



1.7 Timing Characteristics

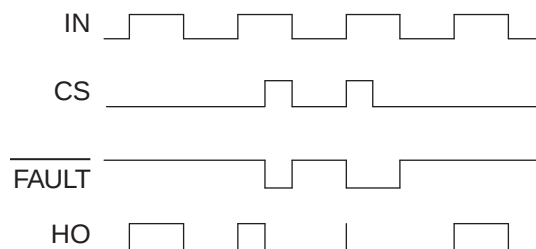
Parameter	Conditions	Symbol	Minimum	Typical	Maximum	Units
Turn-On Propagation Delay	$V_{CC}=V_{BS}=12V$, $C_L=1nF$, $T_A=25^{\circ}C$	t_{on}	-	100	200	ns
Turn-Off Propagation Delay		t_{off}	-	73	200	
Turn-On Rise Time		t_r	-	23	130	
Turn-Off Fall Time		t_f	-	20	65	
Start-Up Blanking Delay		t_{blk}	550	766	950	
CS Shutdown Propagation Delay		t_{CS}	-	220	360	
CS to FLT Propagation Delay		t_{FLT}	-	236	510	

Figure 1. Typical Connection Diagram

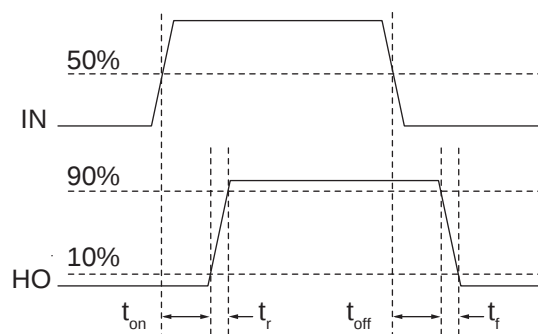




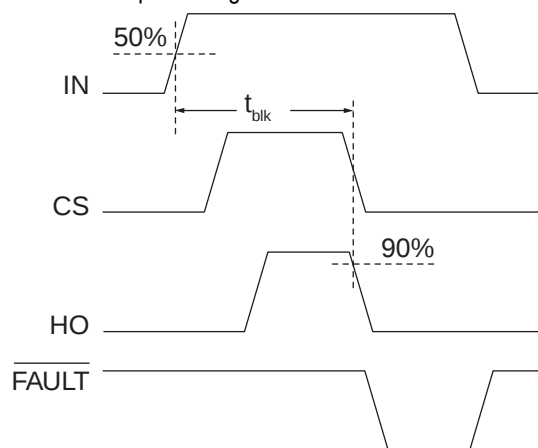
1.7.1 I/O Timing Diagram



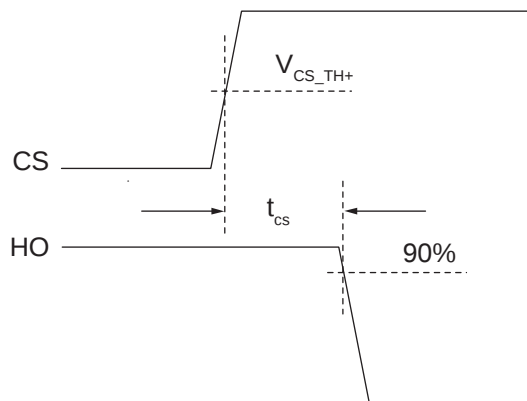
1.7.2 Switching Time Waveforms



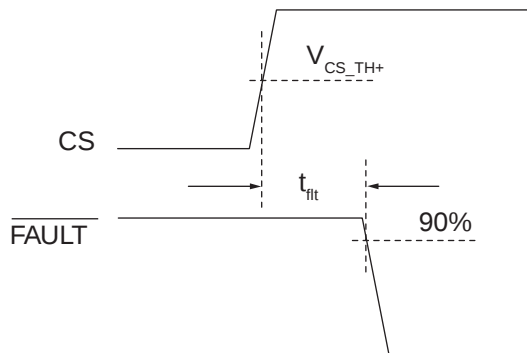
1.7.3 Startup Blanking Time Waveforms



1.7.4 CS Shutdown Waveforms

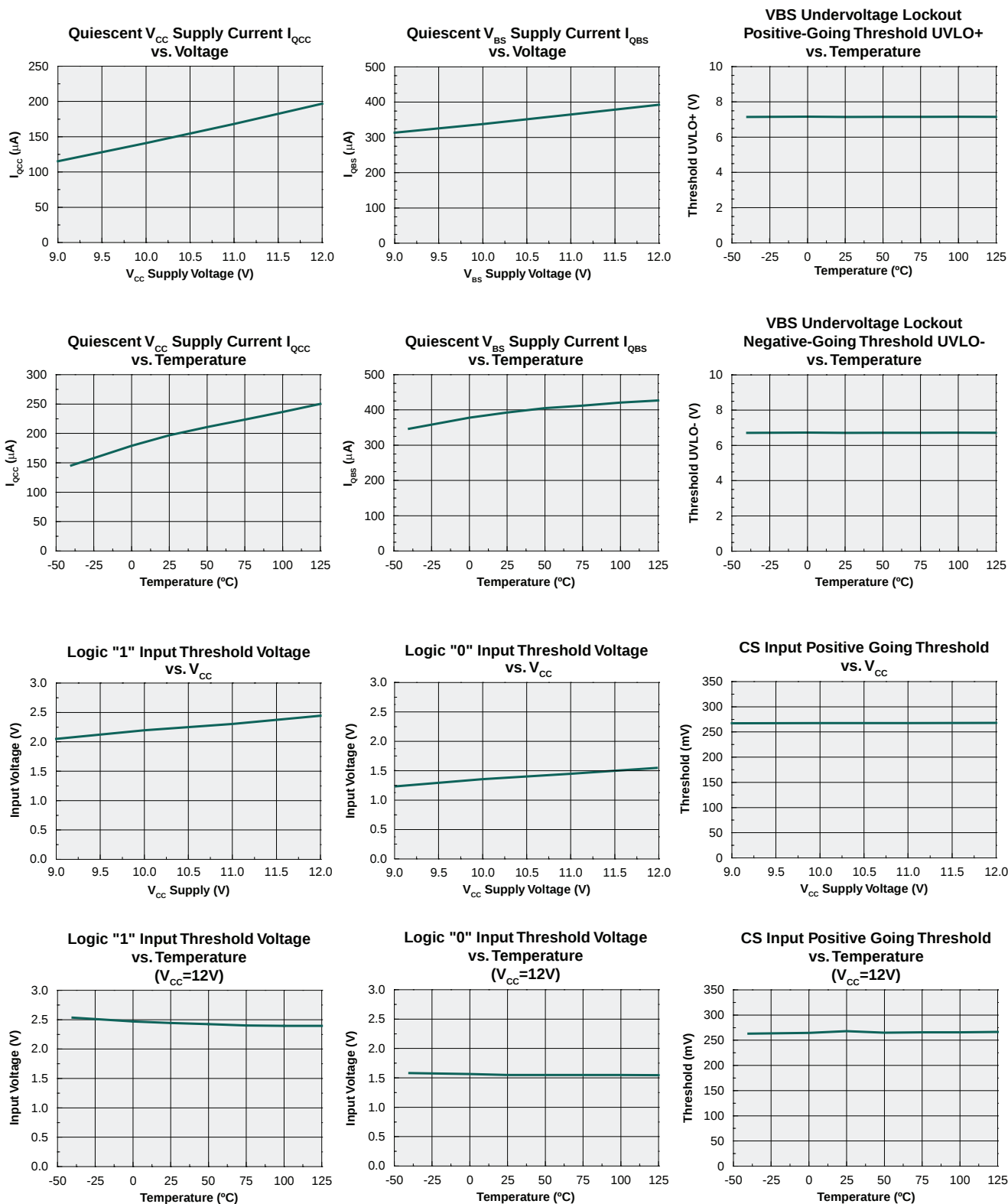


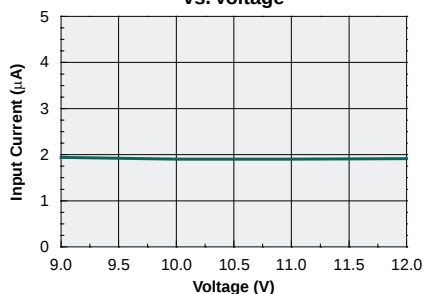
1.7.5 CS to FLT Waveforms



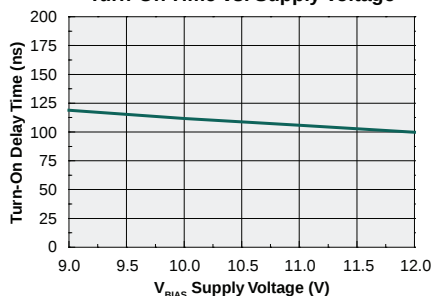
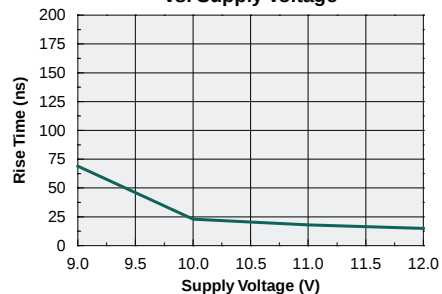
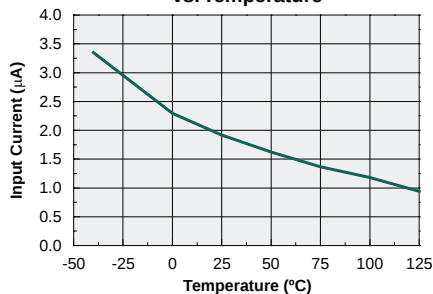
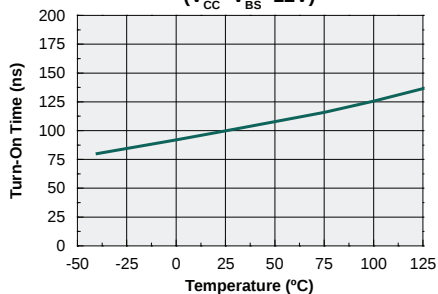
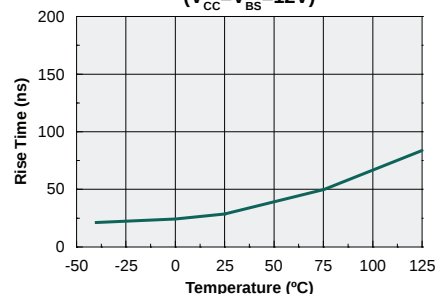
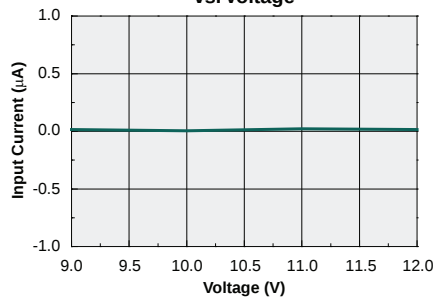


2 Performance Data

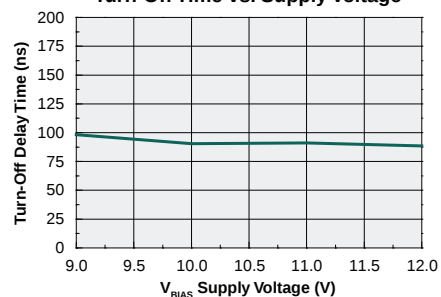
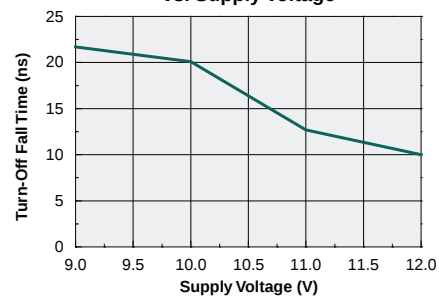
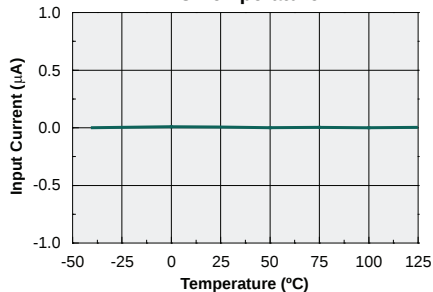
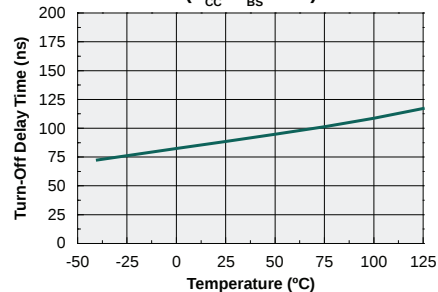
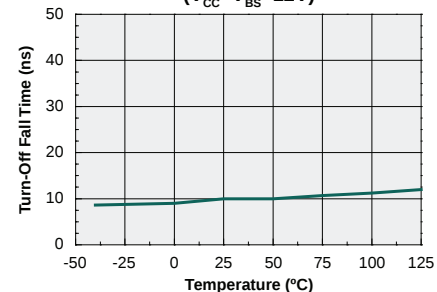


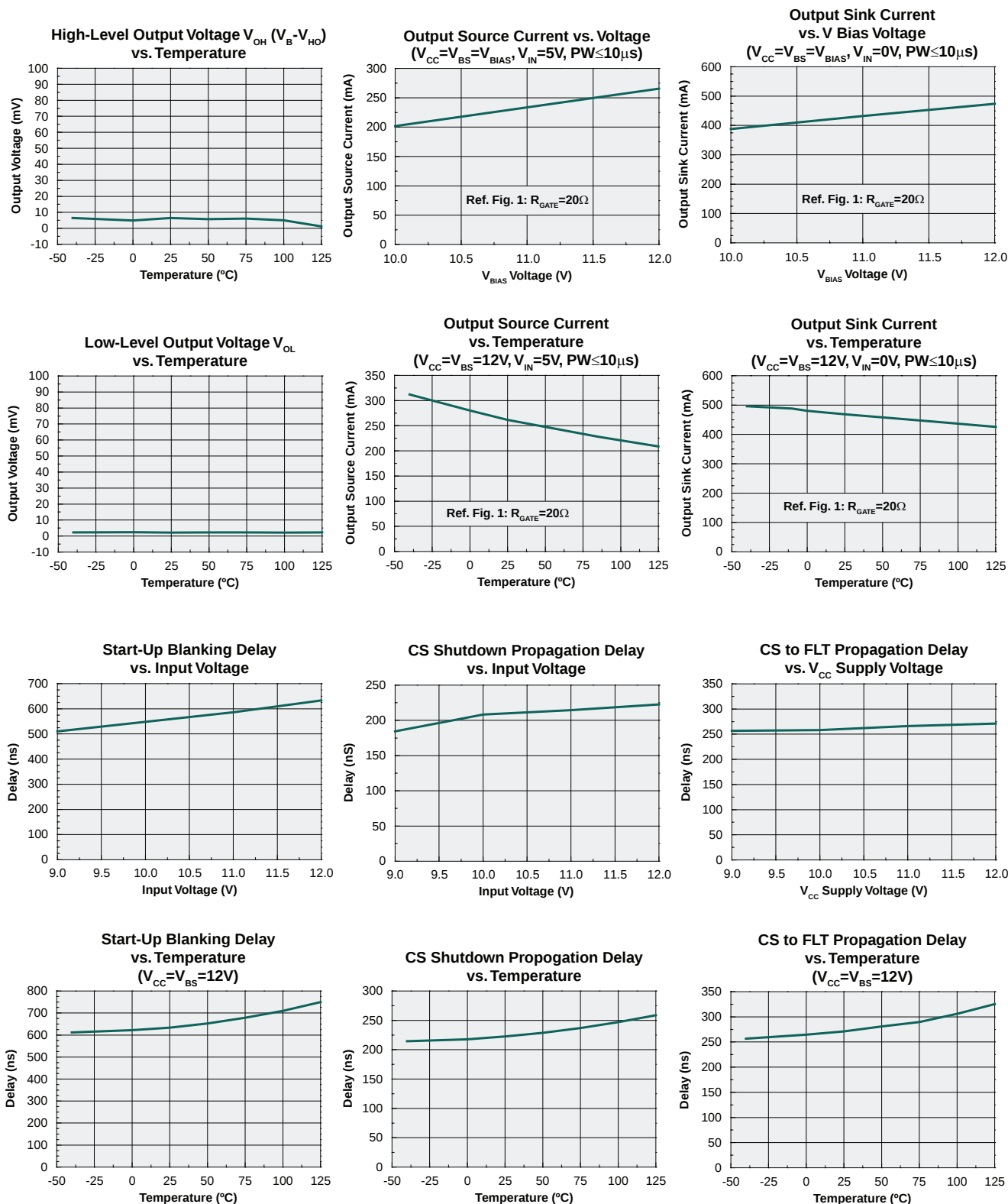
Logic "1" Input Current I_{IN+}
vs. Voltage

Turn-On Time vs. Supply Voltage

Turn-On Rise Time
vs. Supply VoltageLogic "1" Input Current I_{IN+}
vs. TemperatureTurn-On Time vs. Temperature
($V_{CC}=V_{BS}=12V$)Turn-On Rise Time vs. Temperature
($V_{CC}=V_{BS}=12V$)Logic "0" Input Current I_{IN-}
vs. Voltage

Turn-Off Time vs. Supply Voltage

Turn-Off Fall Time
vs. Supply VoltageLogic "0" Input Current I_{IN-}
vs. TemperatureTurn-Off Time vs. Temperature
($V_{CC}=V_{BS}=12V$)Turn-Off Fall Time vs. Temperature
($V_{CC}=V_{BS}=12V$)





3 Manufacturing Information

3.1 Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits Division classifies its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation.

We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL)** classification as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Classification
IX2127G / IX2127N	MSL 1

3.2 ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

3.3 Soldering Profile

Provided in the table below is the Classification Temperature (T_C) of this product and the maximum dwell time the body temperature of this device may be ($T_C - 5^\circ\text{C}$) or greater. The classification temperature sets the Maximum Body Temperature allowed for this device during lead-free reflow processes. For through-hole devices, and any other processes, the guidelines of **J-STD-020** must be observed.

Device	Classification Temperature (T_C)	Dwell Time (t_p)	Max Reflow Cycles
IX2127G	250°C	30 seconds	3
IX2127N	260°C	30 seconds	3

3.4 Board Wash

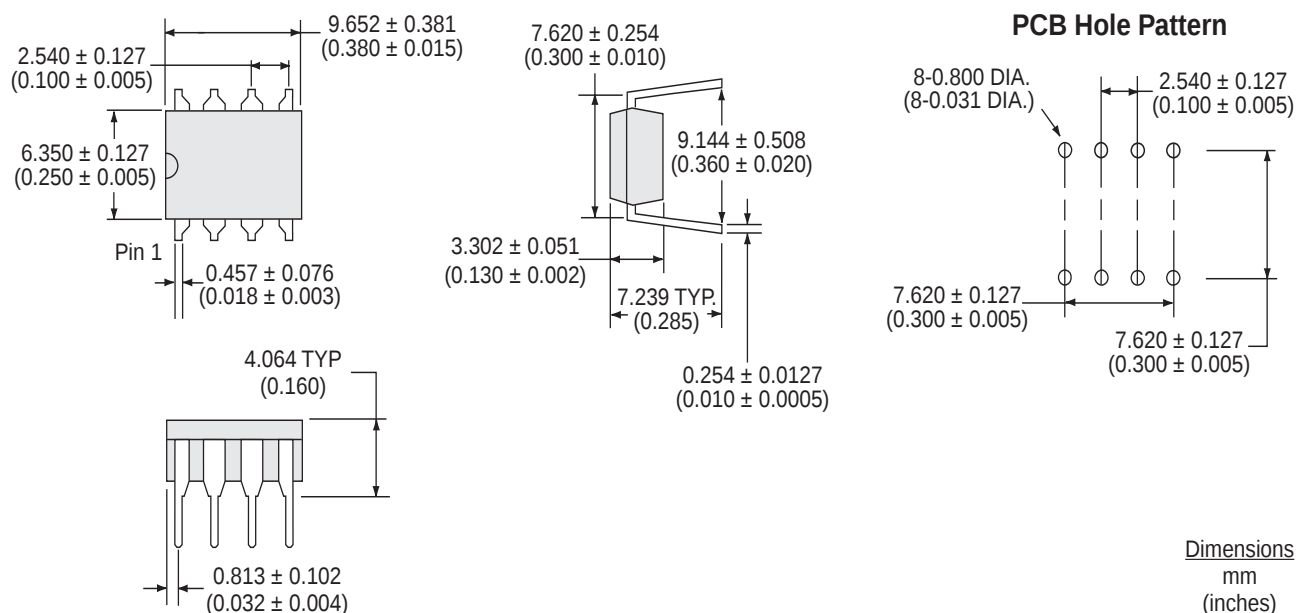
IXYS Integrated Circuits Division recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to flux or solvents that are Chlorine- or Fluorine-based.



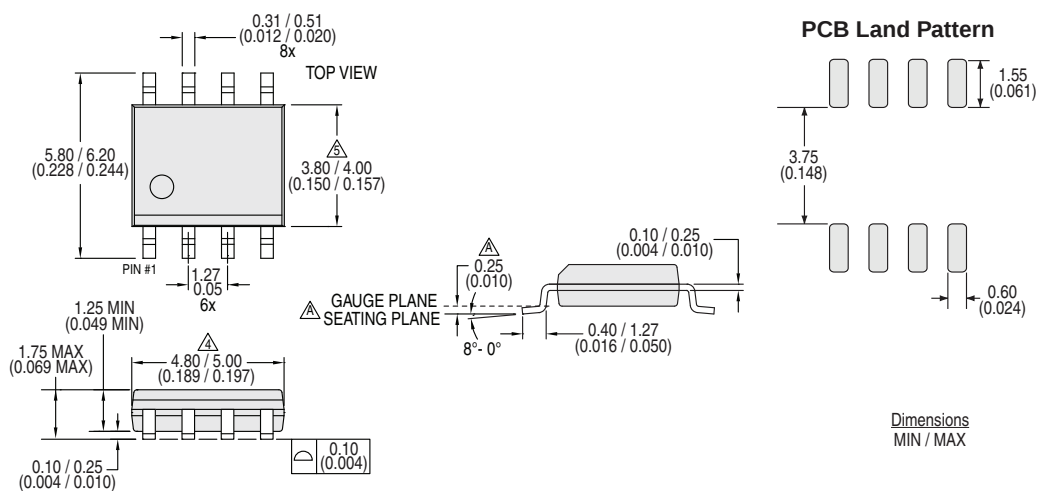


3.5 Mechanical Dimensions

3.5.1 8-Pin DIP Through-Hole Package



3.5.2 8-Pin SOIC Package

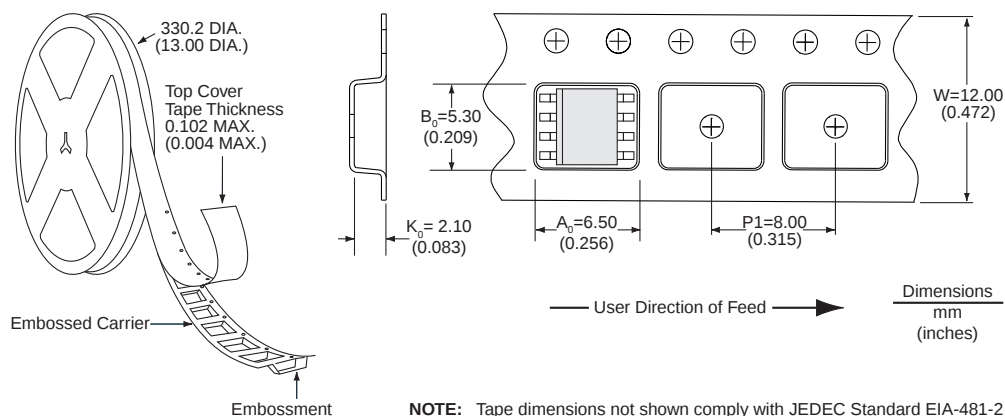


Notes:

1. Controlling dimension: millimeters.
2. All dimensions are in mm (inches).
3. This package conforms to JEDEC Standard MS-012, variation AA, Rev. F.
4. Dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15mm per end.
5. Dimension does not include interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.25mm per side.
6. Lead thickness includes plating.



3.5.3 Tape & Reel Packaging for 8-Pin SOIC Package



For additional information please visit our website at: www.ixysic.com

IXYS Integrated Circuits Division makes no representations or warranties with respect to the accuracy or completeness of the contents of this publication and reserves the right to make changes to specifications and product descriptions at any time without notice. Neither circuit patent licenses or indemnity are expressed or implied. Except as set forth in IXYS Integrated Circuits Division's Standard Terms and Conditions of Sale, IXYS Integrated Circuits Division assumes no liability whatsoever, and disclaims any express or implied warranty relating to its products, including, but not limited to, the implied warranty of merchantability, fitness for a particular purpose, or infringement of any intellectual property right.

The products described in this document are not designed, intended, authorized, or warranted for use as components in systems intended for surgical implant into the body, or in other applications intended to support or sustain life, or where malfunction of IXYS Integrated Circuits Division's product may result in direct physical harm, injury, or death to a person or severe property or environmental damage. IXYS Integrated Circuits Division reserves the right to discontinue or make changes to its products at any time without notice.

Specification: DS-IX2127-R04
©Copyright 2017, IXYS Integrated Circuits Division
All rights reserved. Printed in USA.
10/25/2017